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#	Paper	IF	Citations
115	Antiferroelectric-ferroelectric switching and induced strains for sol-gel derived lead zirconate thin layers. <i>Journal of Applied Physics</i> , <b>1994</b> , 75, 3017-3023	2.5	108
114	Thermodynamics and Kinetics of Surface Area Changes of Faceted Particles. <i>Journal of the American Ceramic Society</i> , <b>1994</b> , 77, 2314-2318	3.8	18
113	TemperatureIIime Texture Transition of Pb(Zr1\(\mathbb{I}\)Tix)O3 Thin Films: I, Role of Pb-rich Intermediate Phases. <i>Journal of the American Ceramic Society</i> , <b>1994</b> , 77, 2332-2336	3.8	214
112	Temperature Time Texture Transition of Pb(Zr1 \( \text{ITix} \) Tin Films: II, Heat Treatment and Compositional Effects. Journal of the American Ceramic Society, <b>1994</b> , 77, 2337-2344	3.8	133
111	Growth and Characterization of PbTiO3 And Pb(Zr,Ti)O3 Thin Films by MOCVD. <i>Materials Research Society Symposia Proceedings</i> , <b>1994</b> , 361, 337		
110	Phase transformations of oriented Pb(Zr1-xTix)O3 thin films from metallo-organic precursors. <b>1994</b> , 152, 25-30		22
109	Thickness dependent dielectric properties of Sol-gel prepared lead lanthanum titanate films. <b>1995</b> , 7, 161-171		6
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2	Low-Temperature Processing. <b>2013</b> , 431-444	
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